## MG2040, SZMG2040

## ESD Protection Diodes

## Low Capacitance ESD Protection for High Speed Video Interface

The MG2040 ESD protection diode is designed specifically to protect HDMI and Display Port with full functionality ESD protection and back drive current protection for $\mathrm{V}_{\mathrm{CC}}$ line. Ultra-low capacitance and low ESD clamping voltage make this device an ideal solution for protecting voltage sensitive high speed data lines. The flow-through style package allows for easy PCB layout and matched trace lengths necessary to maintain consistent impedance for the high speed TMDS lines.

## Features

- Full Function HDMI / Display Port Solution
- Single Connect, Flow through Routing for TMDS Lines
- Low Capacitance ( 0.35 pF Typical, I/O to GND)
- Protection for the Following IEC Standards:

IEC 61000-4-2 Level 4 ( $\pm 8 \mathrm{kV}$ Contact)

- UL Flammability Rating of $94 \mathrm{~V}-0$
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This is a $\mathrm{Pb}-$ Free Device

Typical Applications

- HDMI
- Display Port

MAXIMUM RATINGS $\left(T_{J}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Operating Junction Temperature Range | $\mathrm{T}_{\mathrm{J}}$ | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Lead Solder Temperature <br> Maximum (10 Seconds) | $\mathrm{T}_{\mathrm{L}}$ | 260 | ${ }^{\circ} \mathrm{C}$ |
| IEC 61000-4-2 Contact (ESD) |  |  |  |
| IEC 61000-4-2 Air (ESD) | ESD | $\pm 15$ | kV |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

See Application Note AND8308/D for further description of survivability specs.

ON Semiconductor ${ }^{\circledR}$
www.onsemi.com
(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping |
| :---: | :---: | :---: |
| MG2040MUTAG | UDFN18 <br> (Pb-Free) |  <br> Reel |
| SZMG2040MUTAG | UDFN18 <br> (Pb-Free) |  <br> Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.


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Center Pins, Pin 12, 14, 16, 18
Note: Common GND - Only Minimum of 1 GND connection required


Figure 1. Pin Schematic


Figure 2. Pin Configuration

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise specified)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Reverse Working Voltage | $V_{\text {RWM }}$ | I/O Pin to GND (Note 1) |  |  | 5.0 | V |
| Breakdown Voltage | $V_{B R}$ | $\mathrm{I}_{\mathrm{T}}=1 \mathrm{~mA}, \mathrm{I} / \mathrm{O}$ Pin to GND | 5.5 |  |  | V |
| Reverse Leakage Current | $\mathrm{I}_{\mathrm{R}}$ | $\mathrm{V}_{\mathrm{RWM}}=5 \mathrm{~V}, \mathrm{l} / \mathrm{O}$ Pin to GND |  |  | 1.0 | $\mu \mathrm{A}$ |
| Clamping Voltage (Note 1) | $\mathrm{V}_{\mathrm{C}}$ | $\mathrm{I}_{\mathrm{PP}}=1 \mathrm{~A}, \mathrm{l} / \mathrm{O}$ Pin to GND ( $8 \times 20 \mu \mathrm{~s}$ pulse) |  |  | 10 | V |
| Clamping Voltage (Note 2) | $\mathrm{V}_{\mathrm{C}}$ | IEC61000-4-2, $\pm 8 \mathrm{kV}$ Contact | See Figures 3 and 4 |  |  | V |
| Clamping Voltage <br> TLP (Note 3) <br> See Figures 8 through 11 | $\mathrm{V}_{\mathrm{C}}$ | $\begin{aligned} & \mathrm{IPP}=8 \mathrm{~A} \\ & \mathrm{IPP}=16 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{PP}}=-8 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{PP}}=-16 \mathrm{~A} \end{aligned}$ |  | $\begin{aligned} & \hline 11.4 \\ & 15.3 \\ & -4.6 \\ & -8.1 \end{aligned}$ |  |  |
| Junction Capacitance | C | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ between I/O Pins |  | 0.15 | 0.20 | pF |
|  |  | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ between I/O Pins and GND |  | 0.35 | 0.42 |  |
| Junction Capacitance Difference | $\Delta \mathrm{C}_{\mathrm{J}}$ | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ between I/O Pins |  | 0.02 |  | pF |
|  |  | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ between I/O Pins and GND |  | 0.04 |  |  |

1. Surge current waveform per Figure 7.
2. For test procedure see Figures 5 and 6 and application note AND8307/D.
3. ANSI/ESD STM5.5.1 - Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model. TLP conditions: $\mathrm{Z}_{0}=50 \Omega, \mathrm{t}_{\mathrm{p}}=100 \mathrm{~ns}, \mathrm{t}_{\mathrm{r}}=4 \mathrm{~ns}$, averaging window; $\mathrm{t}_{1}=30 \mathrm{~ns}$ to $\mathrm{t}_{2}=60 \mathrm{~ns}$.


Figure 3. IEC61000-4-2 +8 KV Contact Clamping Voltage


Figure 4. IEC61000-4-2 -8 KV Contact Clamping Voltage

IEC 61000-4-2 Spec.

| Level | Test Volt- <br> age (kV) | First Peak <br> Current <br> $(A)$ | Current at <br> $\mathbf{3 0}$ ns (A) | Current at <br> $\mathbf{6 0}$ ns (A) |
| :---: | :---: | :---: | :---: | :---: |
| 1 | 2 | 7.5 | 4 | 2 |
| 2 | 4 | 15 | 8 | 4 |
| 3 | 6 | 22.5 | 12 | 6 |
| 4 | 8 | 30 | 16 | 8 |



Figure 5. IEC61000-4-2 Spec


Figure 6. Diagram of ESD Clamping Voltage Test Setup

The following is taken from Application Note AND8308/D - Interpretation of Datasheet Parameters for ESD Devices.

## ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger
systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.


Figure $7.8 \times 20 \mu \mathrm{~s}$ Pulse Waveform


Figure 8. Positive TLP I-V Curve

## Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage ( $\mathrm{I}-\mathrm{V}$ ) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 10. TLP I-V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10 s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 11 where an 8 kV IEC 61000-4-2 current waveform is compared with TLP current pulses at 8 A and 16 A . A TLP I-V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels.


Figure 9. Negative TLP I-V Curve


Figure 10. Simplified Schematic of a Typical TLP System


Figure 11. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms


Without ESD


With MG2040

Figure 12. HDMI1.4 Eye Diagram with and without MG2040. 3.4 Gb/s, 400 mV PP


Figure 13. MG2040 Insertion Loss

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Figure 14. HDMI Layout Diagram


UDFN18, $5.5 \times 1.5,0.5 \mathrm{P} / 0.75 \mathrm{P}$
CASE 517CP
ISSUE A
DATE 07 FEB 2013
SCALE 2:1



DETAILA
OPTIONAL construction


BOTTOM VIEW



DETAIL C


NOTES:
. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.10 AND 0.20 MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. EXPOSED ENDS OF TERMINALS ARE ELECTRICALLY ACTIVE.

|  | MILLIMETERS |
| :---: | :---: |
|  |  |

NOTE: CENTER PADS OPTIONAL DIMENSION: MILLIMETERS
*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



END VIEW

|  | MILLIMETERS |  |
| :---: | :---: | :---: |
| DIM | MIN | MAX |
| A | 0.45 | 0.55 |
| A1 | 0.00 | 0.05 |
| A3 | 0.13 |  |
| REF |  |  |
| b | 0.15 |  |
| D | 5.50 |  |
| D2 | 0.25 |  |
| D3 | 0.35 |  |
| E | 0.10 | REF |
| E2 | 0.50 |  |
| eA | 0.50 |  |
| eB | 0.45 |  |
| eC | 1.50 |  |

GENERIC MARKING DIAGRAM*


| XXXX | $=$ Specific Device Code |
| :--- | :--- |
| M | $=$ Date Code |
| - | $=$ Pb-Free Package |

*This information is generic. Please refer to device data sheet for actual part marking.

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| ---: | :--- | :--- | :--- |
| DESCRIPTION: | UDFN18, 5.5X1.5, 0.5P/0.75P | PAGE 1 OF 1 |

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